

HD74LV1GW06A

Dual Inverter Open Drain

REJ03D0075-0100Z (Previous ADE-205-705 (Z)) Rev.1.00 Sep.11.2003

Description

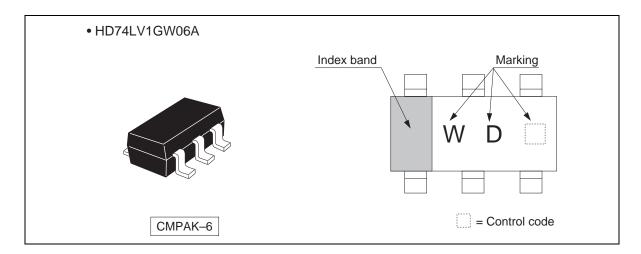
The HD74LV1GW06A has dual inverter open drain in a 6 pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Supply voltage range : 1.65 to 5.5 V Operating temperature range : -40 to +85°C
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V) All outputs V_{O} (Max.) = 5.5 V (@ V_{CC} = 0 V, Output: Z)
- Output current 6 mA (@ $V_{CC} = 3.0 \text{ V}$ to 3.6 V), 12 mA (@ $V_{CC} = 4.5 \text{ V}$ to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV1GW06ACME	CMPAK-6 pin	CMPAK-6V(O)	CM	E (3,000 pcs / Reel)

Outline and Article Indication



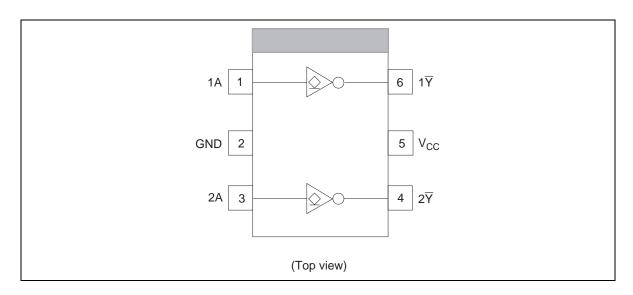
Function Table

Input A	Output Y
Н	L
L	Z

H : High level L : Low level

Z : High impedance

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{CC}	-0.5 to 7.0	V	_
Input voltage range *1	Vı	-0.5 to 7.0	V	
Output voltage range *1, 2	Vo	-0.5 to V _{CC} + 0.5	V	Output : L
		-0.5 to 7.0		V _{CC} : OFF or Output : Z
Input clamp current	I _{IK}	-20	mA	V _I < 0
Output clamp current	I _{OK}	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	Io	±25	mA	$V_{O} = 0$ to V_{CC}
Continuous current through V _{CC} or GND	I _{CC} or I _{GND}	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air) *3	P _T	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{CC}	1.65	5.5	V	
Input voltage range	VI	0	5.5	V	
Output voltage range	Vo	0	V _{CC}	V	
Output current	I _{OL}	_	1	mA	V _{CC} = 1.65 to 1.95 V
		_	2		V_{CC} = 2.3 to 2.7 V
		_	6		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	12		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Input transition rise or fall rate	Δt / Δν	0	300	ns / V	$V_{CC} = 1.65 \text{ to } 1.95 \text{ V}$
		0	200		V_{CC} = 2.3 to 2.7 V
		0	100		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		0	20		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	Ta	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristic

• $Ta = -40 \text{ to } 85^{\circ}\text{C}$

Item	Symbol	V _{CC} (V) *	Min	Тур	Max	Unit	Test condition
Input voltage	V _{IH}	1.65 to 1.95	V _{CC} ×0.75	_	_	V	
		2.3 to 2.7	V _{CC} ×0.7	_	_	_	
		3.0 to 3.6	V _{CC} ×0.7	_	_	_	
		4.5 to 5.5	V _{CC} ×0.7	_	_	_	
	V _{IL}	1.65 to 1.95	_	_	V _{CC} ×0.25	_	
		2.3 to 2.7	_	_	V _{CC} ×0.3	_	
		3.0 to 3.6	_	_	V _{CC} ×0.3	_	
		4.5 to 5.5	_	_	V _{CC} ×0.3	='	
Hysteresis voltage	V _H	1.8	_	0.25	_	V	$V_T^+ - V_T^-$
		2.5	_	0.30	_	_	
		3.3	_	0.35	_	_	
		5.0	_	0.45	_	='	
Output voltage	V _{OL}	Min to Max	_	_	0.1	V	I _{OL} = 50 μA
		1.65	_	_	0.3	_	I _{OL} = 1 mA
		2.3	_	_	0.4	_	I _{OL} = 2 mA
		3.0	_	_	0.44	_	I _{OL} = 6 mA
		4.5	_	_	0.55	_	I _{OL} = 12 mA
Input current	I _{IN}	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Off state output current	loz	Min to Max	_	_	±5	μΑ	$V_0 = 5.5 \text{ V or GND}$
Quiescent supply current	I _{CC}	5.5	_	_	10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
Output leakage current	I _{OFF}	0	_	_	5	μΑ	V_{IN} or $V_O = 0$ to 5.5 V
Input capacitance	C _{IN}	3.3	_	3.0	_	pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

$\bullet \quad V_{CC} = 1.8 \pm 0.15 \ V$

Item	Symbol	Ta = 2	25°C		Ta = -40 to 85°C		Unit		FROM	ТО
		Min	Тур	Max	Min	Max	_	Conditions	(Input)	(Output)
Propagation	t_{ZL}	_	12.6	22.0	1.0	24.0	ns	C _L = 15 pF	Α	Y
delay time	t_{LZ}	_	19.7	33.0	1.0	36.0	-	C _L = 50 pF	-	

$\bullet \quad V_{CC} = 2.5 \pm 0.2 \ V$

Item	Symbol	Ta = 2	25°C		Ta = -40 to 85°C		Unit		FROM	ТО
		Min	Тур	Max	Min	Max	_	Conditions	(Input)	(Output)
Propagation	t_{ZL}	_	7.0	11.7	1.0	14.0	ns	C _L = 15 pF	Α	Y
delay time	t_{LZ}	_	10.5	15.5	1.0	18.0	-	C _L = 50 pF	_	

$\bullet \quad V_{CC} = 3.3 \pm 0.3 \ V$

Item	Symbol	Ta = 2	25°C		Ta = -40 to 85°C		Unit		FROM	ТО
		Min	Тур	Max	Min	Max	_	Conditions	(Input)	(Output)
Propagation	t_{ZL}	_	5.0	7.1	1.0	8.5	ns	C _L = 15 pF	Α	Y
delay time	t_{LZ}	_	7.5	10.6	1.0	12.0	-	C _L = 50 pF	_	

$\bullet \quad V_{CC} = 5.0 \pm 0.5 \ V$

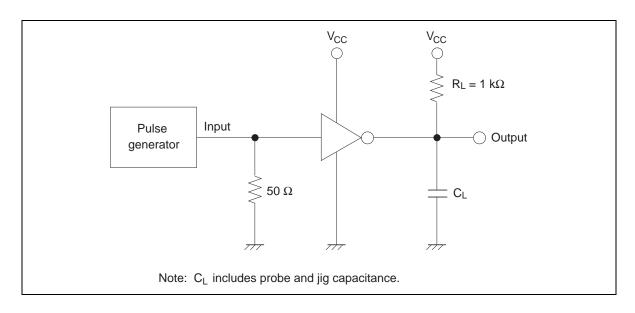
Item	Symbol	Ta = :	25°C		$Ta = -40 \text{ to } 85^{\circ}C$		Unit		FROM	ТО
		Min	Тур	Max	Min	Max	_	Conditions	(Input)	(Output)
Propagation	t _{ZL}	_	3.8	5.5	1.0	6.5	ns	C _L = 15 pF	Α	Y
delay time	t_{LZ}	_	5.3	7.5	1.0	8.5	=	C _L = 50 pF	-	

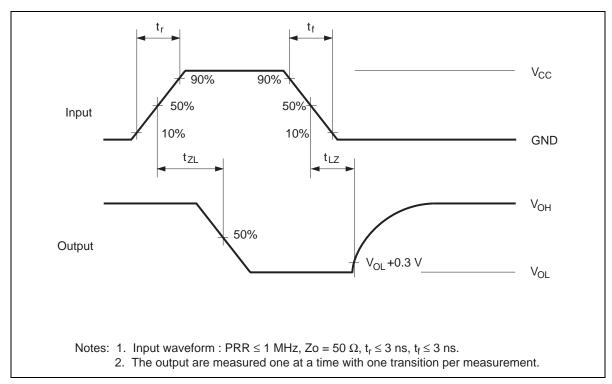
Operating Characteristics

$\bullet \quad C_L = 50 \ pF$

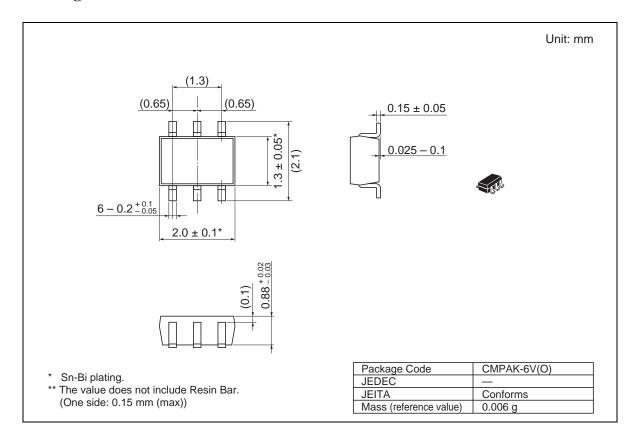
Item	Symbol	V _{CC} (V)	Ta = 25°C			Unit	Test Conditions
			Min	Тур	Max	<u> </u>	
Power dissipation	C_{PD}	3.3	_	8.5	_	pF	f = 10 MHz
capacitance		5.0		10.0	_		

Test Circuit





Package Dimensions



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